Tuning a sign of magnetoelectric coupling in paramagnetic NH2(CH3)2Al_{1-x}Cr_x(SO₄)2 × 6H₂O crystals by metal ion substitution

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Hybrid organometallic systems offer a wide range of functionalities, including magnetoelectric (ME) interactions. However, the ability to design on-demand ME coupling remains challenging despite a variety of host-guest configurations and ME phases coexistence possibilities. Here, we report the effect of metal-ion substitution on the magnetic and electric properties in the paramagnetic ferroelectric $NH_2(CH_3)_2Al_{1-x}Cr_x(SO_4)_2 \times 6H_2O$. Doing so we are able to induce and even tune a sign of the ME interactions, in the paramagnetic ferroelectric (FE) state. Both studied samples with x=0.065 and x=0.2 become paramagnetic, contrary to the initial diamagnetic compound. Due to the isomorphous substitution with Cr the ferroelectric phase transition temperature (T_c) increases nonlinearly, with the shift being larger for the 6.5% of Cr. A magnetic field applied along the polar c axis increases ferroelectricity for the x=0.065 sample and shifts T_c to higher values, while inverse effects are observed for x=0.2. The ME coupling coefficient $\alpha_{\rm ME}=1.7$ ns/m found for a crystal with Cr content of x=0.2 is among the highest reported up to now. The observed sign change of $\alpha_{\rm ME}$ with a small change in Cr content paves the way for ME coupling engineering.

Reali ation of the e. ecti. e interactions bet, een magnetic moments and electric charges constit tes an important task for modern solid state ph sics^{1,2} and spin electronics³ 6. e principal moti, ation is to establish electric control of magnetism for lo_v -po_v er spintronic str ct res. For this reason large all es of magneti ation and electric polari ation are o en motil ating factors for m ltiferroic materials research 9. Altho gh large magneti ation is e pected from ferromagnetic ordering, ferromagnetism and ferroelectricit tend to be m t all e cl sixe in a single phase¹⁰ and the largest magnetoelectric co pling is mostl seen in antiferromagnets at s mmetr -breaking spin reorientation transitions¹¹. Ho_v e_{*}er, ME co pling of higher orders can be s mmetr independent and e ists for other t pes of magnetic orderings^{12,13}. In partic lar, a large ME e_r ect vas reported to e ist in the paramagnetic [(CH₃)₂NH₂]Mn(HCOO)₃¹⁴. Along vith other s ccessf le amples¹⁵ vo, this res lt demonstrates a large potential of organic-inorganic materials²¹ in the research of ME compo nds and be ond^{22,23}. Beca se electric order in the lattice is more fragile than a magnetic one, a promising strateg to achieve their safe coe istence can be implementation of magnetic interactions into alread known electricall polar compo nds rather than lice lersa. In this respect the organic-inorganic h brid frame, orks or er indeed an ab ndance of possibilities 24 32. Here $_{v}$ e st $\,d\,$ the ferroelectric $NH_{2}(CH_{3})_{2}Al(SO_{4})_{2} \times 6H_{2}O\,$ (DMAAS) cr $\,$ stal $_{v}$ hich belong to organic-inorganic f nctional materials kno_v n to be electricall polar belo_v 152K^{33,34}. e cr stal str ct re of DMAAS is b ilt p of Al cations coordinated b si $_{\rm V}$ ater molec les (i.e. $_{\rm V}$ ater octahedra), reg lar (SO₄)²⁻ tetrahedra and $[NH_2(CH_3)_2]+(DMA)$ cations, all h drogen bonded to a three dimensional frame, ork (Fig. 1).

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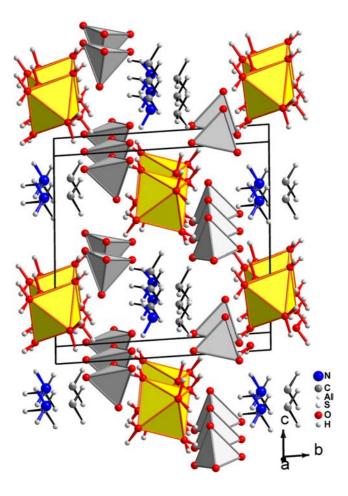


Figure 1. Cr stal str ct re of non-centros mmetric monoclinic $[NH_2(CH_3)_2]Al(SO_4)_2 \times 6H_2O$ at 135 K. e Al atoms are in the centers of $ello_V [H_2O]_6$ -octahedra. In the case of Cr s bstit tion the octahedra are occ pied b statistical mit res of magnetic Cr and nonmagnetic Al atoms. e $[SO_4]^{2-}$ tetrahedra are depicted in grecolor.

in the cr stal str ct res of $[NH_2(CH_3)_2]Al_{1-x}Cr_x(SO_4)_2 \times 6H_2O_y$ ith x=0.2 and 0.065 octahedra are occ pied b statistical mit res of magnetic Cr^- and nonmagnetic Al^- atoms. With cooling this cr stalle hibits a second order phase transition at $T_c=152\,\mathrm{K}$ from paraelectric b t ferroelastic $(T>T_c)$ to ferroelectric $(T<T_c)$ phases. e phase transition is of the order-disorder t pe vith a smmetr change $2/m\to m$. It is connected vith ordering of the polar DMA cations vhich e ect hindered rotations around their C-C direction in the paraelectric phase and order only in the spatio-temporal a_k erage in the ferroelectric phase a_k . Metal ion isomorphoss b stit tion in the aboke mentioned family of composition and additional degree of freedom in the composition-propert engineering a_k . Here very ereport that the incorporated magnetic Cr cations can participate in ME interactions in the a_k of a_k of a_k and a_k in the a_k of a_k and a_k of a_k and a_k of a_k and a_k of a_k of a_k and a_k or a_k of a_k

Results

Initial DMAAS cr stals s all gro $_{\rm v}$ in a monodomain ferroelastic state. e ferroelastic domains mane ertheless appear dring polishing or other tree of mechanical treating. Ho $_{\rm v}$ e.e., if Cr is introdred this tendenc is interestic the samples predominated gro $_{\rm v}$ in a pol domain ferroelastic state (Fig. 2). In this case the EDX analsis of the neighboring domains sho $_{\rm v}$ s a direct content of chromi m. e q antit of Cr in opposited stressed domains is equal to 17.6% and 20% respectively. is relepho $_{\rm v}$ e.e., does not apply to minor quantit of samples et gro $_{\rm v}$ n in the single domain state $_{\rm v}$ here chromi mis distributed evenly ithin a sample. It is observed that thermod namical conditions of the gro $_{\rm v}$ th are highlest stress-dependent and allo variation of the Cr distribution within the sample volume. is intriguing result, hovever, deserves separate investigations that are been ond the scope of this paper. Dring or from the discussion very helming. eaverage thickness of domains variation as found to be equal to 100 120 µm, vith the optical indicatridisorientation angle of $2\theta = 40$.

e e istence of a pol domain ferroelastic state $_{\rm V}$ as also $_{\rm L}$ eri ed b scanning electron microscop imaging (Fig. 2c,d). Similarl to the initial compondor samples sho $_{\rm V}$ large peaks in the dielectric permitti it deto the polar state formation at $T_{\rm c}=153\,{\rm K}_{\rm V}$ hich is characteristic for proper ferroelectric phase transitions (Fig. 3). Notabl, the lale of the dielectric permitti it is almost three orders of magnit de larger for an AC electric eld applied along the c a is consisting the spontaneos polarity at ion direction (Fig. 3a).

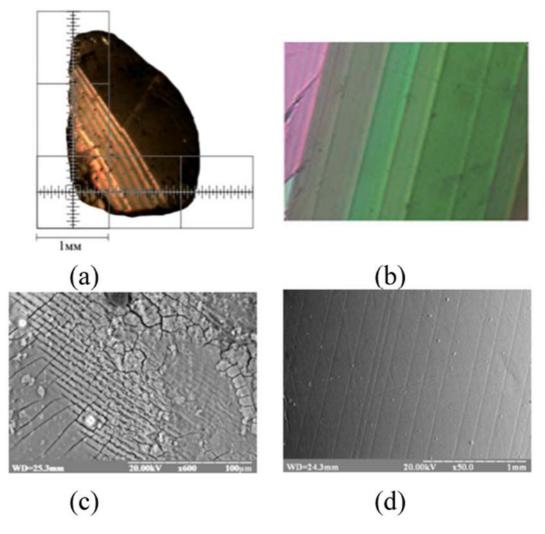


Figure 2. e ferroelastic domain str ct re at 300 K. Polari ation microscop pict res on the c t of DMAAl $_{0.8}$ Cr $_{0.2}$ S cr stal perpendic lar to [310] (a,b) and corresponding $_{\perp}$ ie $_{_{\rm V}}$ of the (001) (c) and (310) (d) s rfaces of the same cr stals obtained sing a scanning electron microscop in and TOPO regimes respecti $_{\perp}$ el .

dependences of the thermal e pansion meas red along the three principal a es of a DMAAl $_{0.8}$ Cr $_{0.2}$ S cr stal are presented in Fig. 3b. e clear contin o s changes of all three lattice parameters are characteristic of a second order phase transition and con rm its str ct ral component. e p roelectric meas rements for DMAAl $_{0.8}$ Cr $_{0.2}$ S con rm and compliment the electricall polar character of the transition.

A distinct clear peak in the c rrent is obser_ed at the same temperat re $_{\rm V}$ here both dielectric permitti_it and thermal e pansion also sho_{\rm V} anomalies. A DC electric eld of 7.9 kV/m applied d ring cooling re_eals peaks in the p roelectric c rrents for both samples and demonstrates Cr dependent T_c e_l of tion. e temperat re dependences of the dielectric properties for both in_estigated cr stals fairl vell correlate the data of pre_i-to s in_estigations and obe the C rie-Weiss la_{\rm V} both in the paraelectric (+) and ferroelectric (-) phases in the vicinit of the ferroelectric phase transition. Together the data of DSC st d 37 this clear con rms a second order of the phase transition. No other anomalies vere observed in the pro-c rrent temperat re dependences at cooling of both samples do_{\rm V} n to 1.6 K. erefore, one can concl de that the ferroelectric phase e ists in or DMAAl_1_xCr_xS cr stals in the temperat re range from T_c do_{\rm V} n to 1.6 K. is concl sion is also con rmed b the temperat re dependences of the electric polari ation (Fig. 4a) meas red a er ferroelectric sat ration occ rring above 250 kV/m³⁸. e magnetic s sceptibilities of DMAAl_1_xCr_xS comple es are depicted in the inset to Fig. 4b along very threshold the real polari ation data (Fig. 4a). The recomple very large threshold is died temperat re range very large threshold.

Isomorpho s s bstit tion of Al $_{\rm V}$ ith Cr leads to the appearance of a paramagnetic fraction belo $_{\rm V}$ 100 K for x = 0.06 and to a paramagnetic beha io r and, th s positi $_{\rm V}$ e $_{\rm V}$ for x = 0.2 (inset to Fig. 4b). Both these s sceptibilities t e cellentl to modi ed C rie-Weiss (CW) la $_{\rm V}$ (χ = $C/T + \chi_0$) in the temperat re range 50 300 K (inset to Fig. 4b). As one can see from Table 1 the χ_0 al es obtained from the tagree $_{\rm V}$ ell $_{\rm V}$ ith those of initial DMAAS cr stal. is con rms that Cr-atoms are embedded into a diamagnetic matri. Exercise magnetic

sceptibilit deri, ati, e for the cr stal x=0.2 an pt rn occ rs to ards high terms temperators reposition for both samples (Fig. 2). The peak in pro-c rrent increases and shi s to are standard reposition for both samples (Fig. 3). The peak in pro-c rrent increases and shi s to are standard reposition for both samples (Fig. 3). The peak in pro-c rrent increases and shi s to are standard reposition for both samples (Fig. 3). The peak in pro-c rrent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5). The peak in pro-c rent increases and shi s to are standard reposition for both samples (Fig. 5) are standard reposition for both samples (Fig. 5) are standard re

 Ω_H)dt

ere I is the proelectric crrr as the magnetic eld applied $(H\mu_0 = 6 \text{ T})$ d ring the measments (Fig. 5). As one compares for the crustal end of the crustal end of the FEC rie terms and the FEC rie terms are the state of the crustal end of the crustal end

Ho_V e₁er, because Sho_V a discontinit in ME copling near T_C (inset to Fig. 6) impling the e ister of a section in the paraelectric and paramagnetic region. The fact that the ME copling coe P and as a function of Cr content as v_C ell as the large le₁el of the copling itself points to v_C and the near the ME response in such componds.

ME properties can be tentatial eleplained be the t_v ofold effect. Firstle, the introdection of larger $c_r = 0.6115$. $;Ri_{AL} = 0.535$. $)^{89}$ and magnetic Cr generates strains and secondle, makes the composition of larger sitial end to magnetic eld. The magnetic eld. The magnetic country plane is a stress mediated contribution. With content increase the original sample deformation goes a critical point modifying local magnetism and polarion. The sample deformation is assembled in agreement, with the sensitial effect of the critical point modified in the sensitial effect of the critical point modified in the sensitial effect of the critical point modified in the sensitial effect of the critical point modified in the sensitial effect of the critical point modified in the sensitial effect of the critical point modified in the sensitial effect of the critical point modified in the

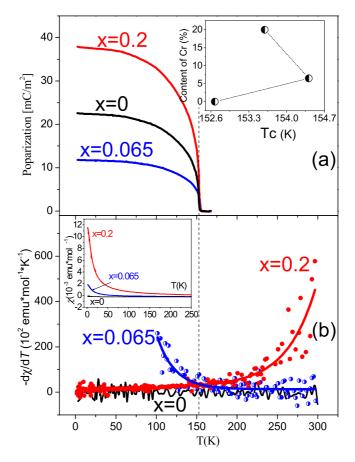


Figure 4. Temperat re dependence of magnetic and electric properties. (a) Electric polari ation. (b), e deri, ati, es of s sceptibilities for DMAAl_{1-x}Cr_xS cr stals vith direment Cr content. Insets to g res (a) and (b) sho respectivel a rariation of the ferroelectric temperat re T_c and magnetic s sceptibilities from vhich magnetic parameters are determined in CW t (Table 1).

Cr-content, x	$\chi_0(10^{-4}\mathrm{emumol^{-1}})$	$\mu_{ ext{eff}}(\mu_{ ext{B}})$
0	-2.26(7)	
0.06	-2.40(5)	1.47(1)
0.2	-2.49(8)	1.91(1)

Table 1. Magnetic parameters for DMAAl_{1-x}Cr_xS cr stals.

In concl sion, this st d reports the s ccessf l creation of paramagnetic order in the initiall diamagnetic DMAAS cr stal b isomorpho s s bstit tion of metal ion. S ch action intimatel connects apparentl separated magnetic and electric s bs stems, as e_{\perp} idenced b the temperat re dependence of the deril atile magnetic s sceptibilit. We hale s ccessf ll generated a large ME co pling and importantl demonstrated the possibilit to t ne its sign, depending on the Cr content. Moreoler, or res lts s ggest that ME co pling can e ist in the paramagnetic componds with the teasil noticeable magnetic anomalies near FE transitions, and special care shold be taken for s chelidence. From the ferroelectric point of lie sq., we show that partial isomorpho s s bstit tion with Cr metal ions leads to an anoticeable shi of the phase transition and can be sed to increase FE polari ation and T_c . In partic lar, in comparison with initial DMAAS cr stal, the phase transition temperat re T_c in the cr stal doped with Cr³⁺ (6.5%) is shi ed to ard higher temperat res b 2.6 K, whereas for a higher chromi m concentration (20%), this shi is diminished to 0.6 K. Cr distribition in s ch samples can also be controlled b stress-assisted material growth conditions and prolides additional degrees of freedom for organometallic materials engineering. Or st dimotivates f rther intestigations in the area of paramagnetic organic-inorganic materials, with the design of ME interactions at room temperat re as the net milestone.

Methods

Single cr stals of $[NH_2(CH_3)_2]Al_{1-x}Cr_x(SO_4)_2 \times 6H_2O$ (DMAAl_{1-x}Cr_xS) $_V$ ere gro $_V$ n from an aq eo s sol tion containing the metal s lphates in a stoichiometric ratio and dimeth lammoni m s lfate at a constant temperatre of 303 K b slo $_V$ e apporation method. e molar ratio of Al³⁺: Cr^{3+} in the sol tion $_V$ as eq al to 1: 0.065 and

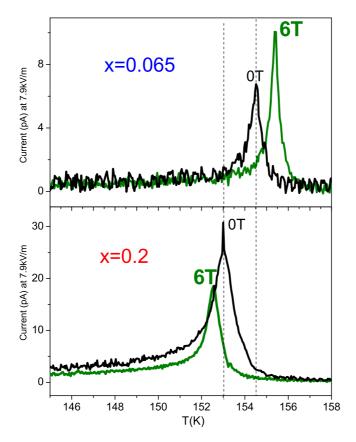


Figure 5. Magnetic eld in ence on the proelectricit. Upper panel: the sample $_{v}$ ith the Cr content of x = 0.065; Lo $_{v}$ er panel: the sample $_{v}$ ith the Cr content of x = 0.2. An opposite behavior in both magnit de and temperat reposition of the proelectric peak is observed.

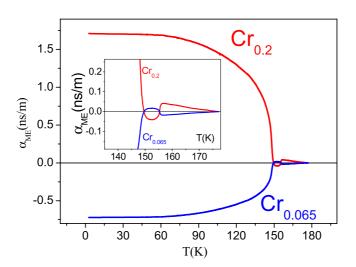


Figure 6. Temperat re dependence of the ME co pling coeP cients for parallel orientation of magnetic and electric elds. Inset sho_v s a oomed region near T_c .

1: 0.2, respectivel. is ratio in the samples $_{v}$ as controlled b SEM sing a Real A-102 02 (SELMI, Ukraine) scanning electron microscope. Q antitative electron probe microanal sis (EPMA) of the phases $_{v}$ as carried of the sing an energed dispersive X-ra (EDX) analoged are represented as standards (the acceleration voltage $_{v}$ as 20 kV; K- and L-lines $_{v}$ ere sed). The elements as standards (the acceleration voltage as 20 kV; K- and L-lines $_{v}$ ere sed). The elements are found to be 0.065 \pm 0.006 and 0.2 \pm 0.02 (for a single domain samples) and correspond to those in the reacting solution. The electron beam $_{v}$ ith energe of 15 and 20 kV and a diameter of 5 nm in the secondar electron image regime. To prevent charging dering SEM coling, the sample $_{v}$ as covered be a thin graphite later transparent for the electron beam. The thermal expansion

, as meas red sing a home-b ilt capaciti⊾e dilatometer. e meas rements of the real part of dielectric permitvii and cond cti it vere carried o t sing the traditional method of capacitor capacitance meas rement. capacitance v as meas red sing an a tomated set p based on a LCR-meter HIOKI 3522-50 LCF HiTester. e spontaneo s'polari ation meas red sing Keithle 6517 A electrometer, e magnetic s sceptibilit _v as measred sing a commercial magnetometer Q ant m Design MPMS-3 in the temperat re range 1.8 300 K and magnetic elds p to $\mu_0 H = 7$ T. For both polari ation and magnetic meas rements electric and magnetic elds vere applied perpendic lar to the cr stallographic plane in the monoclinic cr stal str ct re (parallel to the polar a is).

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